CLAIMS

The following is claimed:

1. An improved method of fabricating a micro-mechanical device, the method comprising:

depositing at least one sacrificial layer on a substrate;

curing the sacrificial layer;

fabricating a micro-mechanical device on the sacrificial layer;

removing the sacrificial layer by immersing the substrate in a cleansing solution comprising super-critical carbon dioxide and a solvent suitable to remove the sacrificial layer.

- A method according to claim 1, wherein the solvent is selected from the group 2. consisting of methanol, ethanol, ethyl acetate, methyl acetate, acetone, methylethylketone, or methyl tertiary-butyl ether.
- 3. A method according to claim 1, wherein the sacrificial layer comprises a 15 photoresist solution.
 - A method according to claim 3, wherein the photoresist solution comprises a 4. mixture of novolac resin and a photoresist solvent.
 - 5. A method according to claim 1, wherein the step of curing the sacrificial layer comprises a hard bake.

- 6. A method according to claim 1, wherein the step of curing the sacrificial layer comprises a soft bake.
- 7. A method according to claim 1, wherein the step of curing the sacrificial layer comprises UV hardening.
- 8. A method according to claim 1, wherein the step of removing the sacrificial layer further comprises agitating the cleansing solution with an impeller.
 - 9. A method according to claim 1, wherein the cleansing solution further comprises a non-ionic surfactant solution.
 - 10. A method according to claim 9, wherein the non-ionic surfactant solution comprises a polystyrene-b-poly(1,1-dihydroperfluorooctyl acrylate) copolymer.
 - 11. An improved method of fabricating a micro-mechanical device, the method comprising:

depositing at least one sacrificial layer on a substrate;

curing the sacrificial layer;

fabricating a micro-mechanical device on the first sacrificial layer:

removing the first sacrificial layer;

recoating the micro-mechanical device with a recoat layer of sufficient thickness to completely encapsulate the micro-mechanical device;

curing the recoat laver;

removing the recoat layer by immersing the substrate in a cleansing solution comprising super-critical carbon dioxide and a solvent suitable to remove the sacrificial layer.

- 12. A method according to claim 11, wherein the solvent is selected from the group
 5 consisting of methanol, ethanol, ethyl acetate, methyl acetate, acetone, methylethylketone, or methyl tertiary-butyl ether.
 - 13. A method according to claim 11, wherein the recoat layer comprises a mixture of novolac resin and a photoresist solvent.
 - 14. A method according to claim 13, wherein the recoat layer does not contain a photoactive compound.
 - 15. A method according to claim 11, wherein the step of curing the recoat layer comprises a hard bake.
 - 16. A method according to claim 11, wherein the step of curing the recoat layer comprises a soft bake.
- 15 17. A method according to claim 11, wherein the step of curing the recoat layer comprises UV hardening.
 - 18. A method according to claim 11, wherein the step of removing the recoat layer further comprises agitating the cleansing solution with an impeller.
- 19. A method according to claim 11, wherein the cleansing solution further comprises a non-ionic surfactant solution.

- A method according to claim 19, wherein the non-ionic surfactant solution 20. comprises a polystyrene-b-poly(1.1-dihydroperfluorooctyl acrylate) copolymer.
- 21. An improved method of fabricating a micro-mechanical device, the method comprising:
- 5 depositing a first sacrificial layer on a substrate;

removing portions of the first sacrificial layer to define a first set of vias;

depositing a first metal layer on the first sacrificial layer:

removing portions of the first metal layer to define a set of first via supports;

depositing a second sacrificial layer on the first metal layer;

removing portions of the second sacrificial layer to define a second set of vias;

depositing a second metal layer on the second sacrificial layer:

removing portions of the second metal layer to define a set of second vias;

removing the first and second sacrificial layers by immersing the substrate in a cleansing solution comprising super-critical carbon dioxide and a solvent suitable to remove the sacrificial layers.

22. A method according to claim 21, wherein the solvent is selected from the group consisting of methanol, ethanol, ethyl acetate, methyl acetate, acetone, methylethylketone, or methyl tertiary-butyl ether.

- 23. A method according to claim 21, wherein the first and second sacrificial layers comprise a photoresist solution.
- 24. A method according to claim 23, wherein the photoresist solution comprises a mixture of novolac resin and a photoresist solvent.
- 5 25. A method according to claim 21, wherein the step of removing the sacrificial layers further comprises agitating the cleansing solution with an impeller.
 - 26. A method according to claim 21, wherein the cleansing solution further comprises a non-ionic surfactant solution.
 - 27. A method according to claim 26, wherein the non-ionic surfactant solution comprises a polystyrene-b-poly(1,1-dihydroperfluorooctyl acrylate) copolymer.
 - 28. An improved method of fabricating a micro-mechanical device, the method comprising:

depositing a first sacrificial layer on a substrate;

removing portions of the first sacrificial layer to define a first set of vias;

depositing a first metal layer on the first sacrificial layer:

removing portions of the first metal layer to define a set of first via supports:

depositing a second sacrificial layer on the first metal layer;

removing portions of the second sacrificial layer to define a set of second via forms:

5

depositing a second metal layer on the second sacrificial layer;

removing portions of the second metal layer to define a set of second via supports:

recoating the micro-mechanical device with a recoat layer of sufficient thickness to completely encapsulate the micro-mechanical device;

curing the recoat layer;

removing the recoat layer by immersing the substrate in a cleansing solution comprising super-critical carbon dioxide and a solvent suitable to remove the recoat layer.

- 29. A method according to claim 28, wherein the solvent is selected from the group consisting of methanol, ethanol, ethyl acetate, methyl acetate, acetone, methylethylketone, or methyl tertiary-butyl ether.
- 30. A method according to claim 28, wherein the recoat layer comprises a mixture of novolac resin and a photoresist solvent.
- 31. A method according to claim 30, wherein the recoat layer does not contain a photoactive compound.
- 32. A method according to claim 28, wherein the step of curing the recoat layer comprises a hard bake.
- 33. A method according to claim 28, wherein the step of curing the recoat layer comprises a soft bake.

- 34. A method according to claim 28, wherein the step of curing the recoat layer comprises UV hardening.
- 35. A method according to claim 28, wherein the step of removing the sacrificial layer further comprises agitating the cleansing solution with an impeller.
- 5 36. A method according to claim 28, wherein the cleansing solution further comprises a non-ionic surfactant solution.
 - 37. A method according to claim 36, wherein the non-ionic surfactant solution comprises a polystyrene-b-poly(1,1-dihydroperfluorooctyl acrylate) copolymer.